

**Over-Voltage-Protection Load Switch internal 6.05V OVP trip level**
**Description**

CFP7014 is an Over-Voltage-Protection (OVP) IC with an ultra-low  $R_{ds(on)}$  high current high voltage MOSFET. It can sustain voltage as high as 36V DC, protecting downstream devices from high voltage surges.

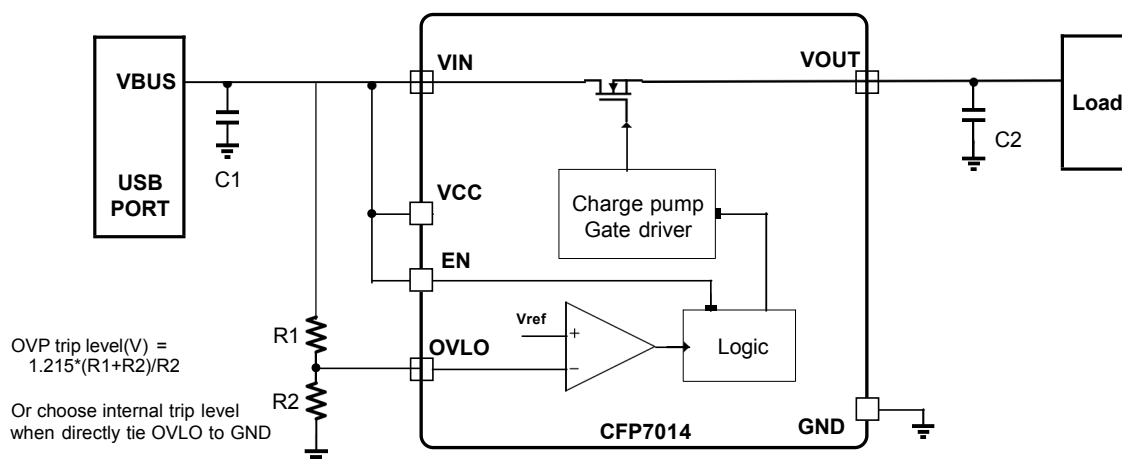
When input voltage of CFP7014 exceed the OVP trip level, it responds quickly and shuts off the MOSFET. The OVP trip level can be externally adjusted with resistors at OVLO pin. It also has an over-temperature protection feature that turns off the MOSFET.

**Applications**

- Mobile Phone
- Mobile handsets
- Portable device
- Notebooks and Tablets

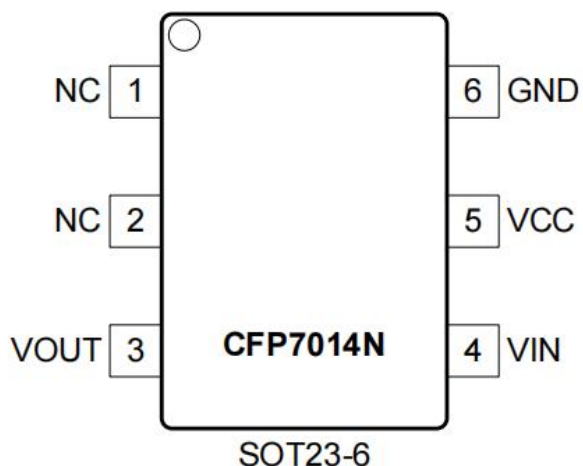
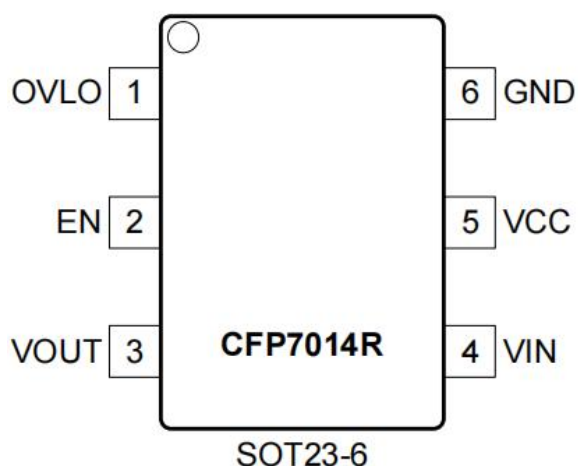
**Features**

- Supply voltage range from 2.7V to 20V
- 36V VBUS voltage tolerance
- Maximum DC switching current up to 3.5A
- Adjustable over voltage protection (OVP)
- 6.05V OVP trip level when OVLO=0V
- Fast turnoff transient response
- Over temperature protection (OTP)
- On chip slew rate control for inrush current
- On-The-Go (OTG) functionality
- ESD:
  - Human Body Model (HBM) > 2kV
  - Charged Device Model (CDM) >750V
  - Machine Model (MM) > 200V
  - IEC61000-4-2 on VBUS pin, Air discharge >15kV
  - IEC61000-4-2 on VBUS pin, contact discharge > 8kV

**Typical Application**

**Order Information**

| Part No. | Package Type | Top Mark  | Pcs/Reel | Internal Bonding Wire |
|----------|--------------|-----------|----------|-----------------------|
| CFP7014R | SOT23-6      | 7014/YWWL | 3000     |                       |
| CFP7014N | SOT23-6      | 7014/YWWL | 3000     | EN=VCC, OVLO=GND      |

## Pin Description



| Pin | R    | N    | I/O | Description                                                                                                                                                                  |
|-----|------|------|-----|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1   | OVLO | /    | I   | OVP feedback input pin. It can be used to adjust the OVP trip level. Or it can be tied to GND to use internal OVP trip level.<br><b>Caution:</b> cannot float for CFP7014R ! |
| 2   | EN   | /    | I   | Enable pin. Pull high to turn on the chip and pull low to shut down the chip.<br><b>Caution:</b> cannot float for CFP7014R !                                                 |
| 3   | 3    | VOUT | O   | OUTPUT pin. Bypass with a 1uF capacitor from this pin to ground.                                                                                                             |
| 4   | 4    | VIN  | I   | Voltage Input. Bypass with a 0.1uF/50V ceramic capacitor as close to the device as possible.                                                                                 |
| 5   | 5    | VCC  | P   | The independent supply voltage for control logic and charge pump, tied to IN in normal application                                                                           |
| 6   | 6    | GND  | G   | GND                                                                                                                                                                          |

## Absolute Maximum Ratings

| Parameter                     | Rating         | Unit | Remarks   |
|-------------------------------|----------------|------|-----------|
| VCC, VIN Voltage              | -0.3 ~ 36      | V    |           |
| EN, OVLO Voltage              | -0.3 ~ VCC+0.3 | V    |           |
| VOUT                          | -0.3 ~ 24      | V    |           |
| Continuous switch current     | <4             | A    | Tamb=25°C |
| Operational temperature range | -40 ~ 85       | °C   |           |
| Storage temperature range     | -55 ~ 150      | °C   |           |
| ESD Air Gap                   | 15             | KV   |           |
| ESD Contact                   | 8              | KV   |           |
| ESD HBM                       | 2.5            | KV   |           |
| ESD CDM                       | 0.5            | KV   |           |

## Recommended Operating Condition

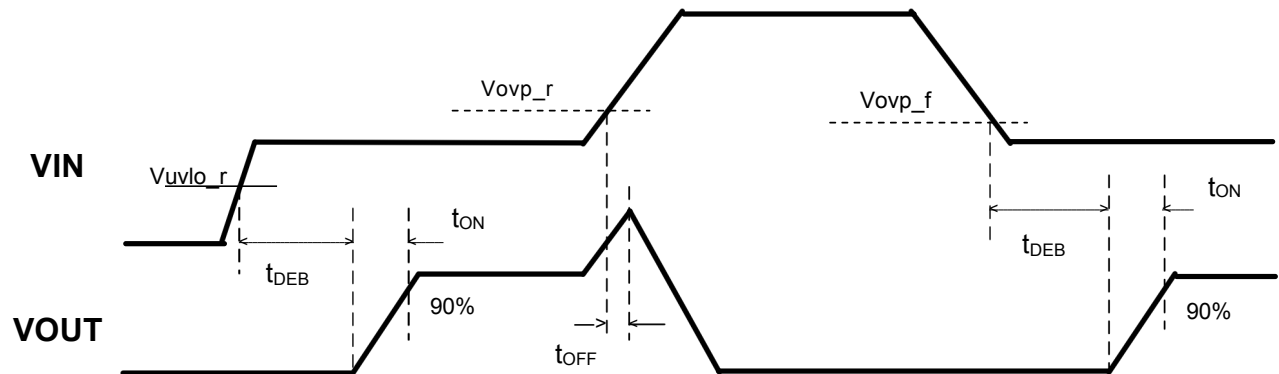
| Parameter                     | Rating     | Unit | Remarks |
|-------------------------------|------------|------|---------|
| VBUS Voltage                  | 3 ~ 20     | V    |         |
| Ambient Operating Temperature | -40 ~ 85°C | V    |         |
| VOUT Load Capacitor           | <1000      | μF   |         |

## Electrical Characteristics

Test conditions: Tamb=25°C, VBUS=5V unless otherwise noted.

| Parameter                        | Symbol               | Min   | Typ   | Max   | Unit | Conditions         |
|----------------------------------|----------------------|-------|-------|-------|------|--------------------|
| Quiescent Current                | I <sub>Q</sub>       | 50    | 68    | 120   | μA   | VBUS=5V, OVLO=0V   |
| Internal OVP trip level          | V <sub>ovp_r</sub>   | 5.9   | 6.05  | 6.25  | V    | VBUS rise, OVLO=0V |
|                                  | V <sub>ovp_f</sub>   | 5.75  | 5.9   | 6.1   | V    | VBUS fall, OVLO=0V |
| Adjustable OVLO threshold        | V <sub>ovp_rng</sub> | 4     |       | 20    | V    |                    |
| Threshold voltage at OVLO        | V <sub>ovlo</sub>    | 1.185 | 1.215 | 1.245 | V    |                    |
| Under voltage lockout trip level | V <sub>uvlo_r</sub>  | 2.3   | 2.47  | 2.6   | V    | VBUS rise, OVLO=0V |
|                                  | V <sub>uvlo_f</sub>  | 2.15  | 2.3   | 2.5   | V    | VBUS fall, OVLO=0V |
| Resistance from VBUS to VOUT     | R <sub>dson</sub>    |       | 50    | 70    | mΩ   | MOSFET on          |
| Leakage current on OVLO          | I <sub>L_ovlo</sub>  |       |       | 2     | μA   |                    |
| Over temperature protection      |                      |       | 130   |       | °C   |                    |
| Over temperature hysteresis      |                      |       | 20    |       | °C   |                    |
| Debounce Time                    | t <sub>DEB</sub>     |       | 16    |       | ms   |                    |
| VOUT rise time                   | t <sub>ON</sub>      |       | 1.5   |       | ms   |                    |
| OVLO turn off time               | t <sub>OFF</sub>     |       | 100   |       | ns   | RL=100Ω, CL=0μF    |
| Start-up Time                    | t <sub>START</sub>   |       | 30    |       | ms   |                    |

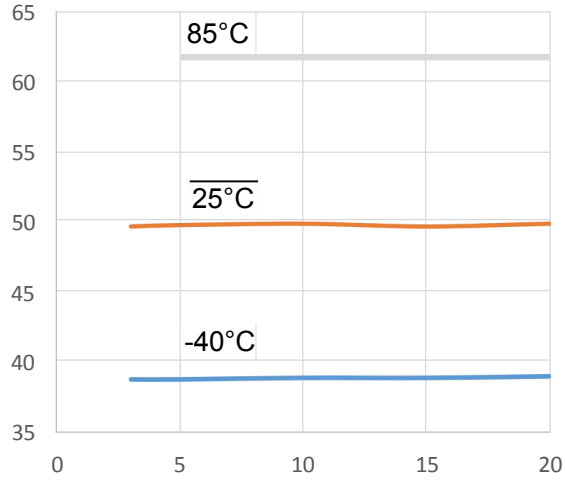
## Timing Diagrams



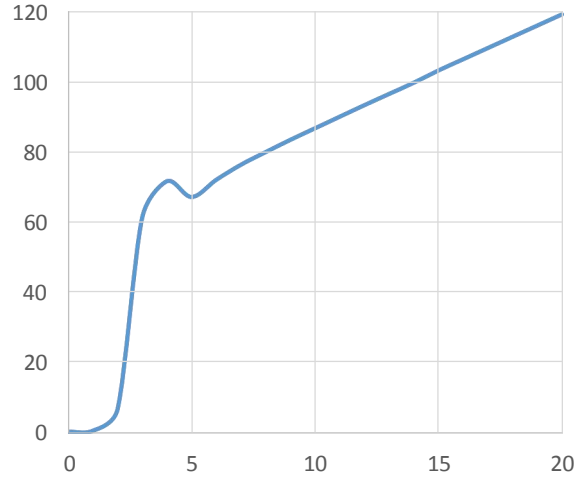
## Typical Characteristics

Test conditions:  $T_{amb}=25^{\circ}\text{C}$ ,  $V_{BUS}=5\text{V}$ ,  $C_{IN}=C_{OUT}=1\mu\text{F}$ , unless otherwise noted.

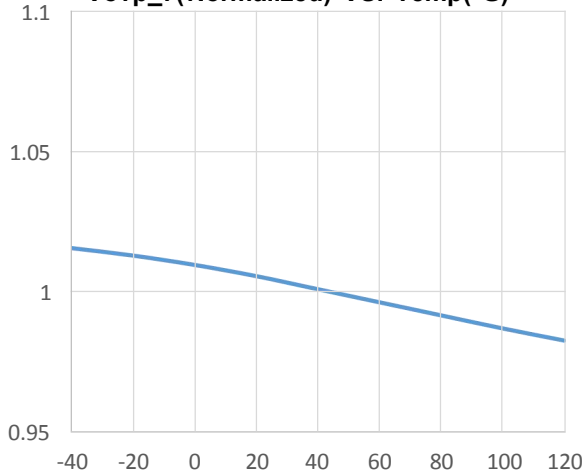
**$R_{dson}(m\Omega)$  VS.  $V_{CC}(V)$**



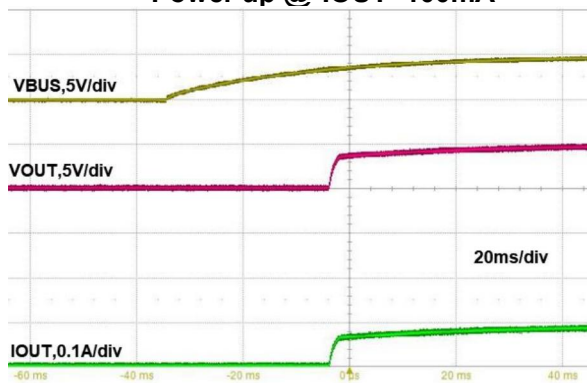
**$I_Q(\mu\text{A})$  VS.  $V_{CC}(V)$**



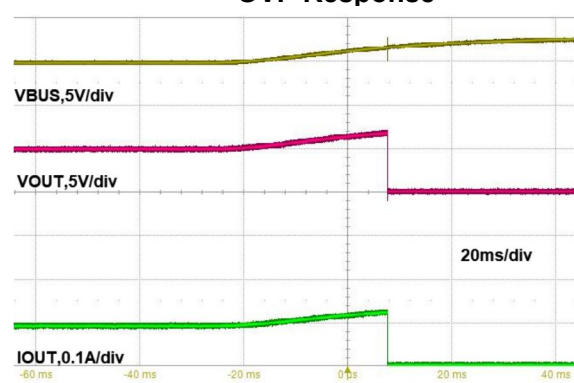
**$V_{ovp\_r}(\text{Normalized})$  VS. Temp( $^{\circ}\text{C}$ )**



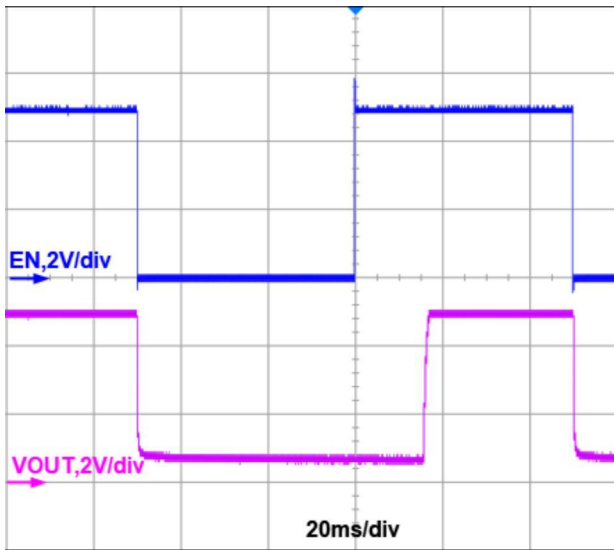
**Power up @  $I_{OUT}=100\text{mA}$**



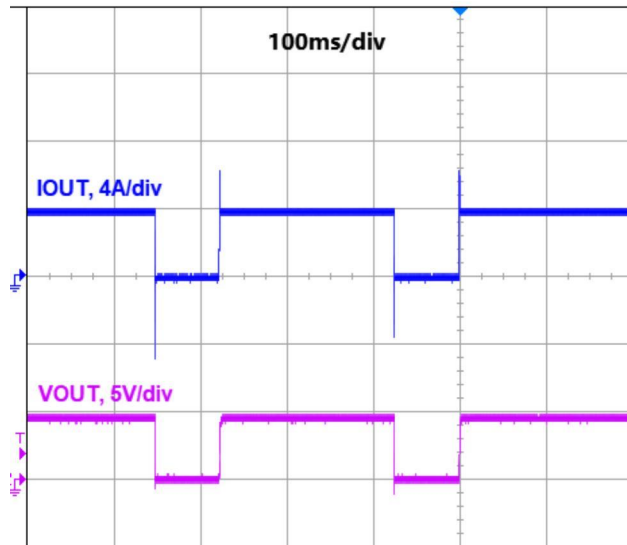
**OVP Response**



**EN Function**

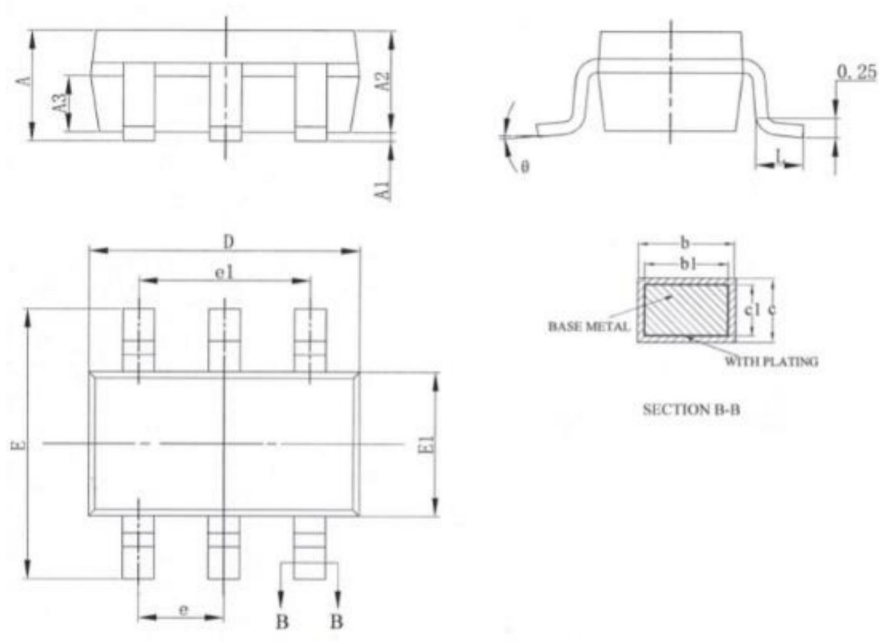


**OTP Function**



## Package Outline

SOT23-6



| SYMBOL | MILLIMETER |      |      |
|--------|------------|------|------|
|        | MIN        | NOM  | MAX  |
| A      | —          | —    | 1.25 |
| A1     | 0.04       | —    | 0.10 |
| A2     | 1.00       | 1.10 | 1.20 |
| A3     | 0.55       | 0.65 | 0.75 |
| b      | 0.38       | —    | 0.48 |
| b1     | 0.37       | 0.40 | 0.43 |
| c      | 0.11       | —    | 0.21 |
| c1     | 0.10       | 0.13 | 0.16 |
| D      | 2.72       | 2.92 | 3.12 |
| E      | 2.60       | 2.80 | 3.00 |
| E1     | 1.40       | 1.60 | 1.80 |
| e      | 0.95BSC    |      |      |
| e1     | 1.90BSC    |      |      |
| L      | 0.30       | —    | 0.60 |
| θ      | 0          | —    | 8°   |